# 1. General description

NPN/NPN Resistor-Equipped Transistor (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PQMD13

# 2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- · Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs

# 3. Applications

- Low current peripheral driver
- Control of IC inputs
- · Replaces general-purpose transistors in digital applications
- · Mobile applications

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	

[1] See section "Test information" for resistor calculation and test conditions.



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	1 7 6	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2	2 5	TR2
5	12	input (base) TR2	3 8 4	R2 R1
6	01	output (collector) TR1		
7	01	output (collector) TR1	Transparent top view	
8	O2	output (collector) TR2	DFN1010B-6 (SOT1216)	GND1 I1 O2 aaa-019894

# 6. Ordering information

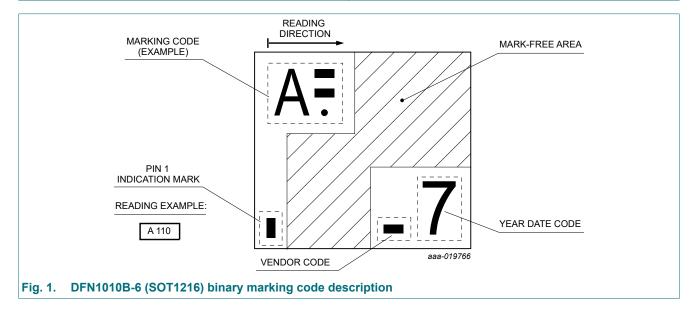
**Table 3. Ordering information** 

Type number Package				
	Name	Description	Version	
PQMH13		plastic, leadless thermal enhanced ultra thin small outline package; 6 terminals; 0.35 mm pitch; 1.1 mm x 1 mm x 0.37 mm body	SOT1216	

# 7. Marking

Table 4. Marking codes

Type number	Marking code
PQMH13	A
	100



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

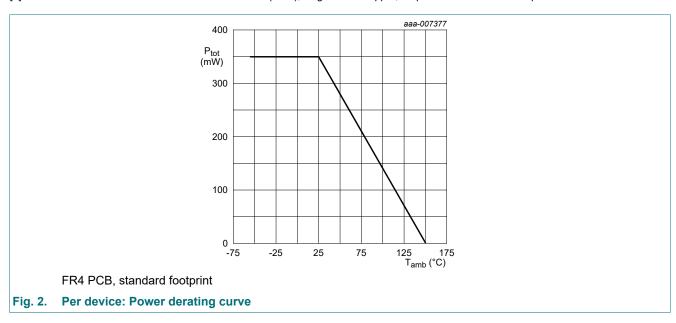
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'	<u> </u>		
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
$V_{CEO}$	collector-emitter voltage	open base		-	50	V
$V_{EBO}$	emitter-base voltage	open collector		-	5	V
VI	input voltage			-5	30	V
Io	output current			-	100	mA
I <sub>CM</sub>	peak collector current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
Per device	'			'		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

# 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

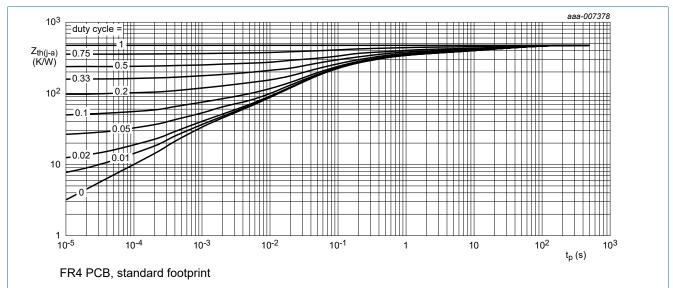


Fig. 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

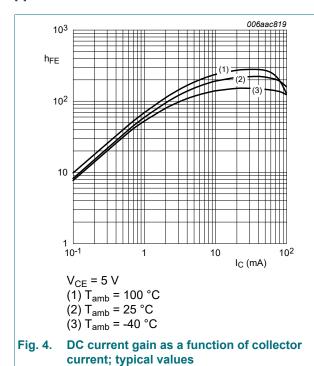
#### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

# 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
I <sub>CEO</sub> collector-emitter cut-off	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	170	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; T <sub>amb</sub> = 25 °C		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-	0.6	0.5	V
V <sub>I(on)</sub>	on-state input voltage	V <sub>CE</sub> = 0.3 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C		1.3	0.9	-	V
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



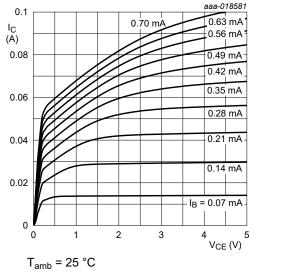
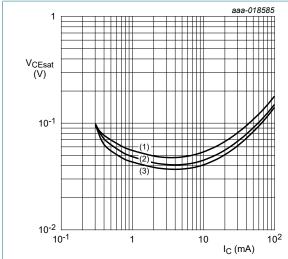


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

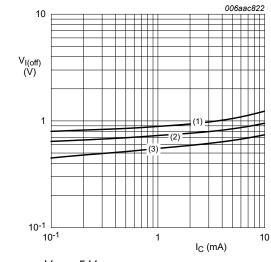


$$I_{\rm C}/I_{\rm B} = 20$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



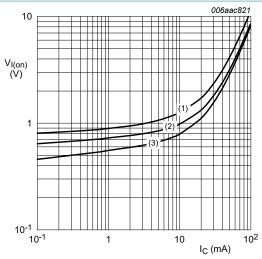
$$V_{CE}$$
 = 5  $V$ 

(1) 
$$T_{amb} = -40 \,^{\circ}\text{C}$$
  
(2)  $T_{amb} = 25 \,^{\circ}\text{C}$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 8. Off-state input voltage as a function of collector current; typical values

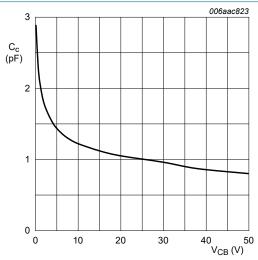


$$V_{CF} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

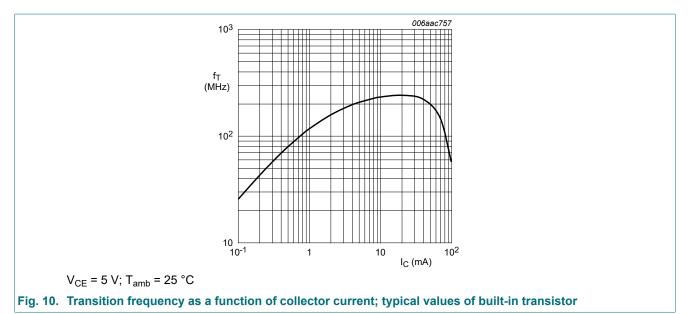
Fig. 7. On-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$ 

Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$



11. Test information

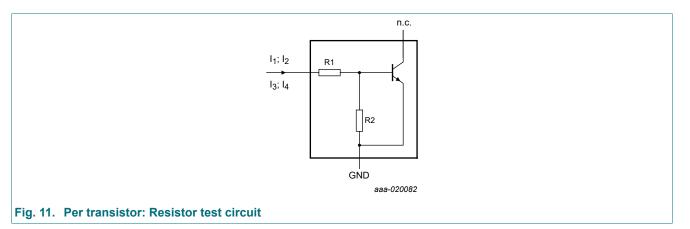
### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - \frac{1}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - \frac{1}{R1} = \frac{1}$$



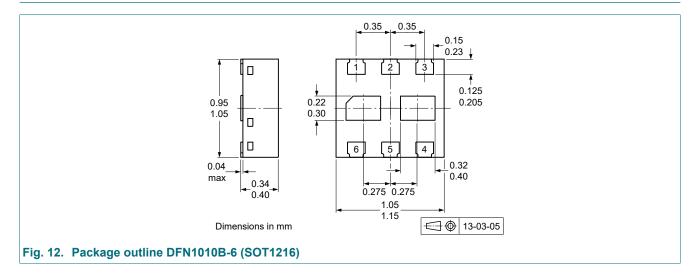
#### **Resistor test conditions**

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14
PQMH13	4.7	47	90 μΑ	140 µA	-55 μΑ	-105 µA

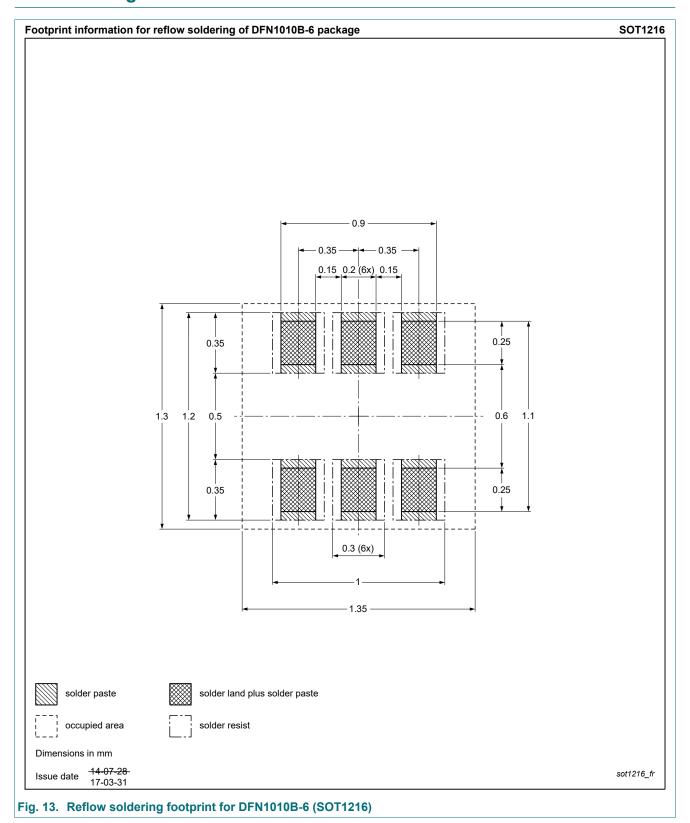
NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

# 12. Package outline



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

# 13. Soldering



### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

# 14. Revision history

### Table 9. Revision history

	,					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PQMH13 v.2	20241008	Product data sheet	-	PQMH13 v.1		
Modifications:	\ /	<ul> <li>Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).</li> </ul>				
PQMH13 v.1	20151104	Product data sheet	-	-		

#### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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### NPN/NPN resistor-equipped double transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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